

**Rectifier diodes  
Schottky barrier**

**PBYR745 series**

**FEATURES**

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

**SYMBOL**



**QUICK REFERENCE DATA**

$V_R = 40\text{ V} / 45\text{ V}$
$I_{F(AV)} = 7.5\text{ A}$
$V_F \leq 0.57\text{ V}$

**GENERAL DESCRIPTION**

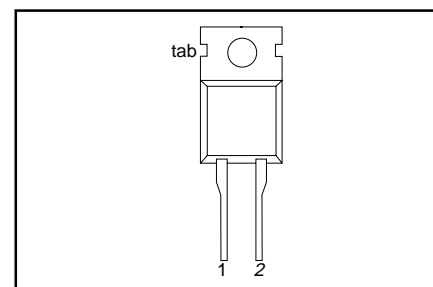
Schottky rectifier diodes in a plastic envelope. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR745 series is supplied in the conventional leaded SOD59 (TO220AC) package.

**PINNING**

PIN	DESCRIPTION
1	cathode
2	anode
tab	cathode

**SOD59 (TO220AC)**



**LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
		<b>PBYR7</b>			
$V_{RRM}$	Peak repetitive reverse voltage		-	40	V
$V_{RWM}$	Working peak reverse voltage		-	40	V
$V_R$	Continuous reverse voltage	$T_{mb} \leq 114\text{ }^\circ\text{C}$	-	40	V
$I_{F(AV)}$	Average rectified forward current	square wave; $\delta = 0.5$ ; $T_{mb} \leq 136\text{ }^\circ\text{C}$	-	7.5	A
$I_{FRM}$	Repetitive peak forward current	square wave; $\delta = 0.5$ ; $T_{mb} \leq 136\text{ }^\circ\text{C}$	-	15	A
$I_{FSM}$	Non-repetitive peak forward current	$t = 10\text{ ms}$ $t = 8.3\text{ ms}$ sinusoidal; $T_j = 125\text{ }^\circ\text{C}$ prior to surge; with reapplied $V_{RRM(max)}$ pulse width and repetition rate limited by $T_{jmax}$	-	135	A
			-	150	A
$I_{RRM}$	Peak repetitive reverse surge current		-	1	A
$T_j$	Operating junction temperature		-	150	$^\circ\text{C}$
$T_{stg}$	Storage temperature		- 65	175	$^\circ\text{C}$

**THERMAL RESISTANCES**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base		-	-	3	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	in free air	-	60	-	K/W

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**ELECTRICAL CHARACTERISTICS** $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 7.5\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	0.45	0.57	V
		$I_F = 15\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	0.65	0.72	V
		$I_F = 15\text{ A}$	-	0.64	0.84	V
$I_R$	Reverse current	$V_R = V_{RWM}$	-	0.13	1	mA
		$V_R = V_{RWM}; T_j = 100\text{ }^\circ\text{C}$	-	17	22	mA
$C_d$	Junction capacitance	$V_R = 5\text{ V}; f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C to } 125\text{ }^\circ\text{C}$	-	270	-	pF

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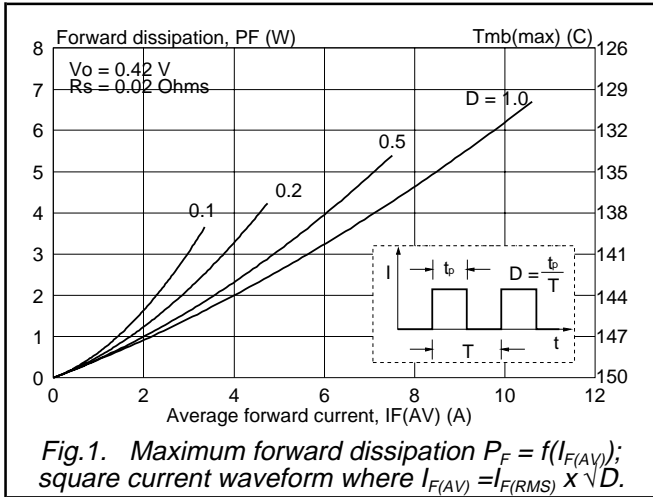


Fig.1. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; square current waveform where  $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

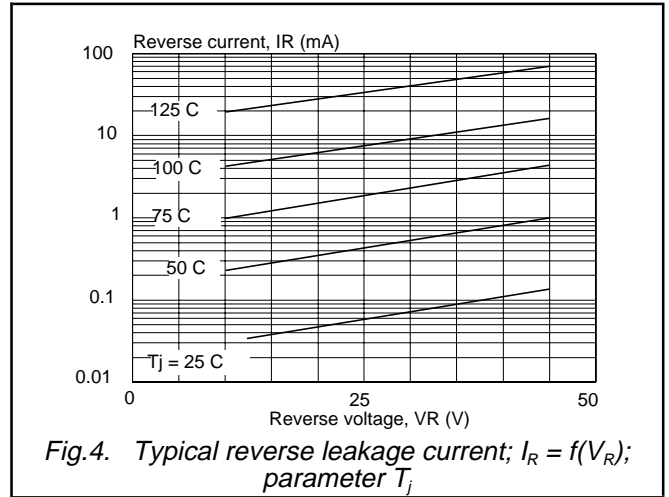


Fig.4. Typical reverse leakage current;  $I_R = f(V_R)$ ; parameter  $T_j$ .

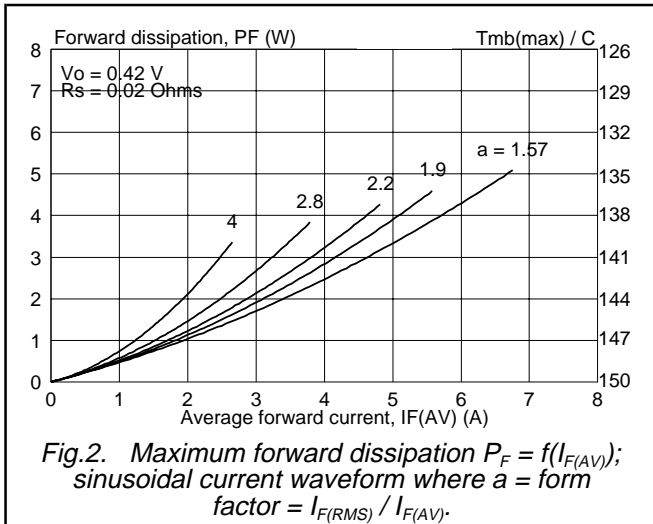


Fig.2. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where  $a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$ .

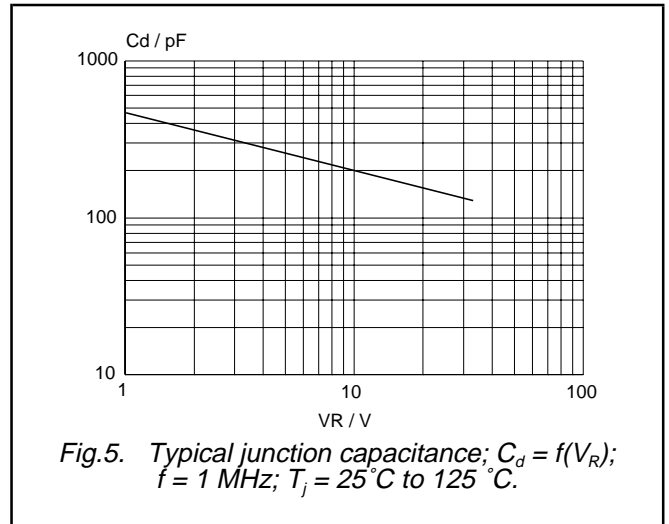


Fig.5. Typical junction capacitance;  $C_d = f(V_R)$ ;  $f = 1\text{ MHz}$ ;  $T_j = 25^\circ\text{C}$  to  $125^\circ\text{C}$ .

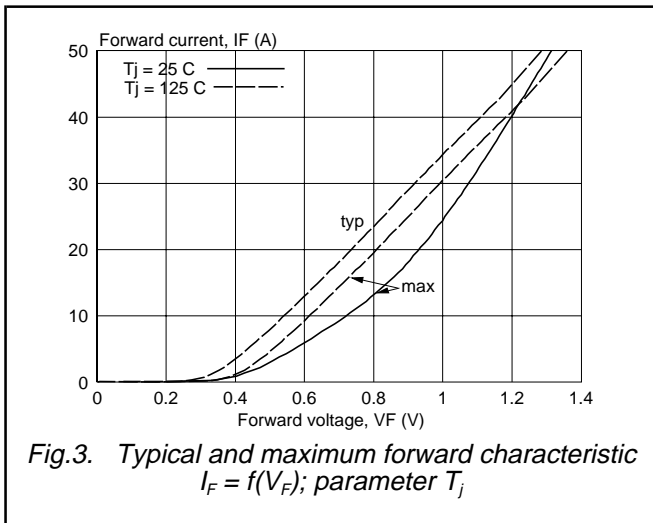


Fig.3. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ .

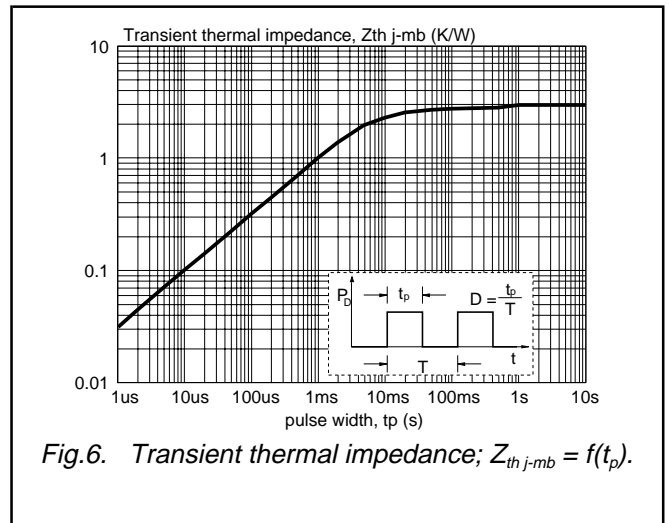
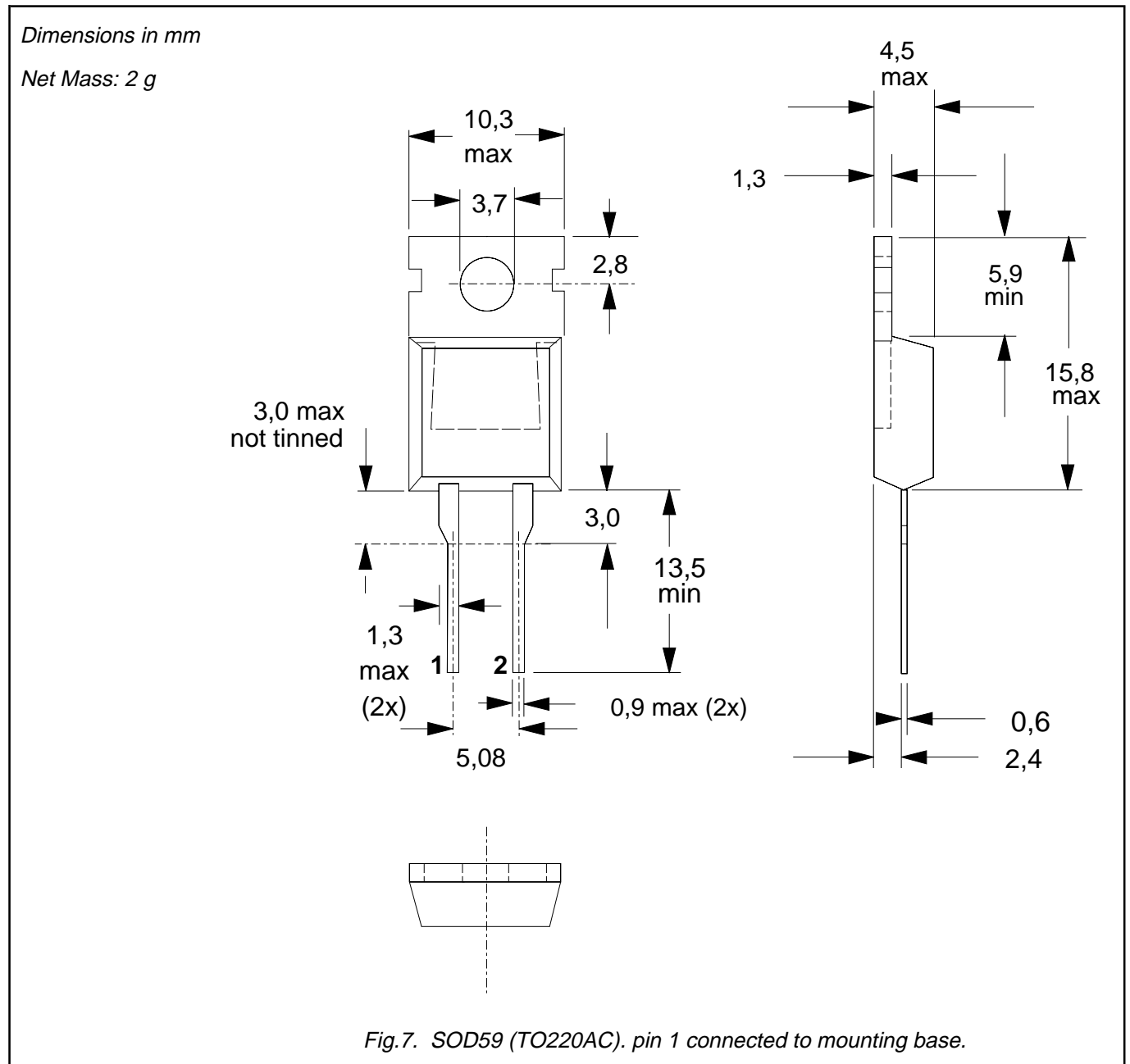


Fig.6. Transient thermal impedance;  $Z_{th\ j-mb} = f(t_p)$ .

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**MECHANICAL DATA**



**Notes**

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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## DEFINITIONS

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	
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